Octal D-type flip-flop with reset; positive-edge triggerRev. 4 — 10 June 2013Product of

Product data sheet

1. **General description**

The 74HC273; 74HCT273 is an octal positive-edge triggered D-type flip-flop. The device features clock (CP) and master reset (MR) inputs. The outputs Qn will assume the state of their corresponding Dn inputs that meet the set-up and hold time requirements on the LOW-to-HIGH clock (CP) transition. A LOW on MR forces the outputs LOW independently of clock and data inputs. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. **Features and benefits**

- Input levels:
 - For 74HC273: CMOS level
 - For 74HCT273: TTL level
- Common clock and master reset
- Eight positive edge-triggered D-type flip-flops
- Complies with JEDEC standard no. 7A
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V.
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

Ordering information 3.

Table 1. **Ordering information**

Type number	Package	Package										
	Temperature range	Name	Description	Version								
74HC273N	–40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1								
74HCT273N												
74HC273D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1								
74HCT273D												
74HC273DB	–40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads; body width	SOT339-1								
74HCT273DB			5.3 mm									

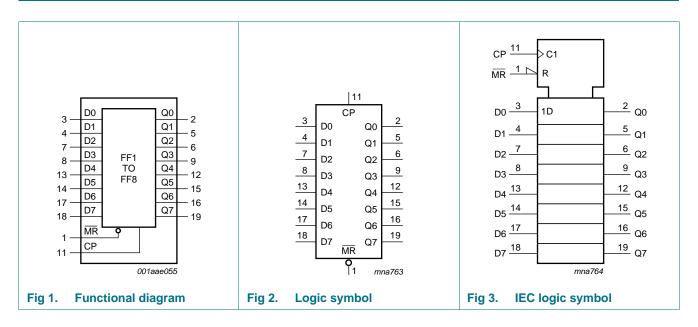


Octal D-type flip-flop with reset; positive-edge trigger

Type number	Package									
	Temperature range	Name	Description	Version						
74HC273PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body	SOT360-1						
74HCT273PW			width 4.4 mm							
74HC273BQ	–40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin	SOT764-1						
74HCT273BQ			quad flat package; no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm							

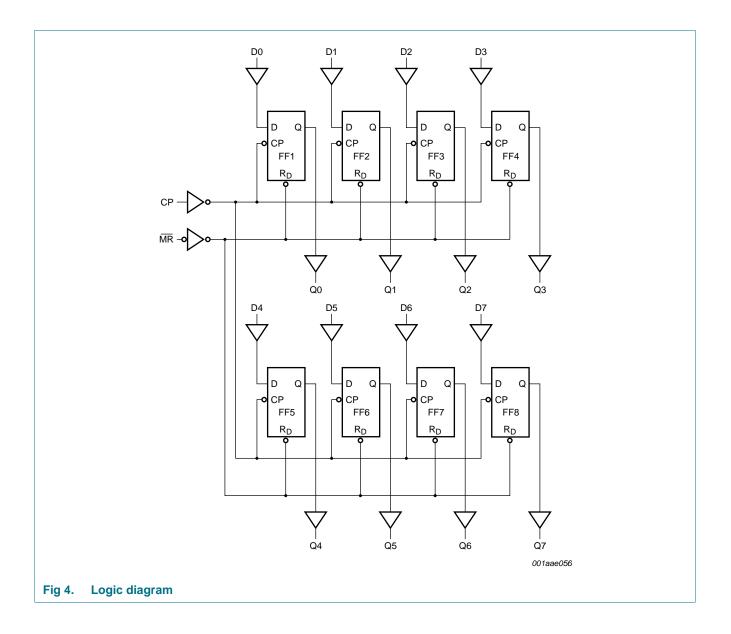
Table 1. Ordering information ...continued

4. Functional diagram



74HC273; 74HCT273

Octal D-type flip-flop with reset; positive-edge trigger



Octal D-type flip-flop with reset; positive-edge trigger

5. Pinning information

74HC273 74HCT273 Vcc terminal 1 MR index area 20 -74HC273 (19 Q0 2 Q7 74HCT273 D0 3) (18 D7 MR 1 20 V_{CC} D1 4) (17 D6 Q0 2 19 Q7 (16 Q1 5) Q6 D0 3 18 D7 Q2 6) (15 Q5 D1 4 17 D6 16 Q6 Q1 5 D2 7) (14 D5 GND⁽¹⁾ Q2 6 15 Q5 8) (13 D3 D4 D2 7 14 D5 9) (12 Q4 Q3 13 D4 D3 8 P E 12 Q4 Q3 9 GND Ч 001aae054 GND 10 11 CP Transparent top view 001aae053 (1) This is not a supply pin. The substrate is attached to this pad using conductive die attach material. There is no electrical or mechanical requirement to solder this pad. However, if it is soldered, the solder land should remain floating or be connected to GND. Fig 5. Pin configuration DIP20, SO20, SSOP20 and Fig 6. **Pin configuration DHVQFN20** TSSOP20

5.1 Pinning

5.2 Pin description

Table 2. Pin description		
Symbol	Pin	Description
MR	1	master reset input (active LOW)
Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7	2, 5, 6, 9, 12, 15, 16, 19	flip-flop output
D0, D1, D2, D3, D4, D5, D6, D7	3, 4, 7, 8, 13, 14, 17, 18	data input
GND	10	ground (0 V)
СР	11	clock input (LOW-to-HIGH, edge-triggered)
V _{CC}	20	supply voltage

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6. Functional description

Table 3. Function table^[1]

Operating modes	Inputs	Inputs						
	MR	Dn	Qn					
reset (clear)	L	Х	Х	L				
load "1"	Н	↑	h	Н				
load "0"	Н	↑	I	L				

[1] H = HIGH voltage level;

h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level;

I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

X = don't care;

 \uparrow = LOW-to-HIGH clock transition.

7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
Ι _{ΟΚ}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
lo	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C			
		DIP20 package	[2] _	750	mW
		SO20, SSOP20, TSSOP20 and DHVQFN20 package	<u>[3]</u> _	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For DIP20 package: above 70 °C the value of Ptot derates linearly with 12 mW/K.

[3] For SO20 package: above 70 °C the value of P_{tot} derates linearly with 8 mW/K.
 For SSOP20 and TSSOP20 packages: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K.
 For DHVQFN20 packages: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

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8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	-	74HC273	3	7	Unit		
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 ℃	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC27	3								1	
V _{IH}	HIGH-level	$V_{CC} = 2.0 V$	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	-	1.8	V
V _{ОН}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	I_{O} = -20 μ A; V_{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I_{O} = -20 μ A; V_{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V
		I_{O} = -4.0 mA; V_{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I_{O} = -5.2 mA; V_{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	I_{O} = 20 μ A; V_{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I_{O} = 5.2 mA; V_{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1	-	±1	μΑ
lcc	supply current		-	-	8.0	-	80	-	160	μΑ

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Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 °C	Uni
			Min	Тур	Max	Min	Max	Min	Max	-
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT2	73									
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{он}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = 20 \ \mu\text{A}; \ V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 5.2 mA; V_{CC} = 5.5 V	-	0.15	0.26	-	0.33	-	0.4	V
1	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	-	±1	-	±1	μA
lcc	supply current		-	-	8.0	-	80	-	160	μA
∆I _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V								
		MR input	-	100	360	-	450	-	490	μA
		CP input	-	175	630	-	787.5	-	857.5	μA
		Dn input	-	15	54	-	67.5	-	73.5	μA
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit, see <u>Figure 10</u>

Symbo	I Parameter	Conditions		25 °C		-40 °C to	o +85 °C	–40 °C to	+125 °C	Unit
				Тур	Max	Min	Max	Min	Max	
74HC27	73									
t _{pd}	propagation	CP to Qn; see Figure 7								
	delay	$V_{CC} = 2.0 V$	-	41	150	-	185	-	225	ns
		$V_{CC} = 4.5 V$	-	15	30	-	37	-	45	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	15	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$	-	13	26	-	31	-	38	ns

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Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	–40 °C to +125 °C		Unit
Cymbol	i arameter		-	Min	Тур	Max	Min	Max	Min	Max	Unit
t	HIGH to LOW	MR to Qn; see Figure 8		141111	тур	IVIAA	IVIIII	Wax	IVIIII	IVIAA	
t _{PHL}	propagation	$V_{CC} = 2.0 V$			44	150	-	185		225	ns
	delay			-		30			-		
		$V_{CC} = 4.5 V$			16	30	-	37	-	45	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	15	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$	[2]	-	14	26	-	31	-	38	ns
tt	transition time	Qn output; see <u>Figure 7</u>	[2]		40	75		05		44.0	
		$V_{CC} = 2.0 V$		-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 V$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 V$		-	6	13	-	15	-	19	ns
t _W	pulse width	CP input HIGH or LOW; see <u>Figure 7</u>									
		$V_{CC} = 2.0 V$		80	14	-	100	-	120	-	ns
		$V_{CC} = 4.5 V$		16	5	-	20	-	24	-	ns
		$V_{CC} = 6.0 V$		14	4	-	17	-	20	-	ns
		MR input LOW; see <u>Figure 8</u>									
		$V_{CC} = 2.0 V$		60	17	-	75	-	90	-	ns
		V _{CC} = 4.5 V		12	6	-	15	-	18	-	ns
		V _{CC} = 6.0 V		10	5	-	13	-	15	-	ns
t _{rec}	recovery time	MR to CP; see Figure 8									
		V _{CC} = 2.0 V		50	-6	-	65	-	75	-	ns
		V _{CC} = 4.5 V		10	-2	-	13	-	15	-	ns
		V _{CC} = 6.0 V		9	-2	-	11	-	13	-	ns
t _{su}	set-up time	Dn to CP; see Figure 9									
		V _{CC} = 2.0 V		60	11	-	75	-	90	-	ns
		V _{CC} = 4.5 V		12	4	-	15	-	18	-	ns
		$V_{CC} = 6.0 V$		10	3	-	13	-	15	-	ns
h	hold time	Dn to CP; see Figure 9									
		$V_{CC} = 2.0 V$		3	-6	-	3	-	3	-	ns
		V _{CC} = 4.5 V		3	-2	-	3	-	3	-	ns
		$V_{CC} = 6.0 V$		3	-2	-	3	-	3	-	ns
max	maximum	CP input; see Figure 7		-	_		-		-		-
Παλ	frequency	$V_{\rm CC} = 2.0 \text{ V}$		6	20.6	-	4.8	-	4	-	MH
		$V_{\rm CC} = 4.5 \text{ V}$		30	103	-	24	-	20	-	MH
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	66	-		_	-	-	MH
		$V_{CC} = 6.0 V$		35	122	-	28	-	24	-	MH
C _{PD}	power dissipation	$v_{CC} = 0.0 v$ per package; $V_I = GND$ to V_{CC}	<u>[3]</u>	-	20	-	-	-	-	-	pF

Table 7. Dynamic characteristics ...continued

GND (around = 0 V); $C_1 = 50 \text{ pF}$ unless otherwise specified; for test circuit, see Figure 10

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Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	o +125 ℃	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HCT27	73									
t _{pd}	propagation	CP to Qn; see Figure 7	l							
	delay	$V_{CC} = 4.5 V$	-	16	30	-	38	-	45	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	15	-	-	-	-	-	ns
t _{PHL}	HIGH to LOW	MR to Qn; see Figure 8								
	propagation delay	$V_{CC} = 4.5 V$	-	23	34	-	43	-	51	ns
	uelay	$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	20	-	-	-	-	-	ns
t _t	transition time	Qn output; see Figure 7	1							
		$V_{CC} = 4.5 V$	-	7	15	-	19	-	22	ns
t _W	pulse width	CP input; see Figure 7								
		$V_{CC} = 4.5 V$	16	9	-	20	-	24	-	ns
		MR input LOW; see <u>Figure 8</u>								
		$V_{CC} = 4.5 V$	16	8	-	20	-	24	-	ns
t _{rec}	recovery time	MR to CP; see Figure 8								
		$V_{CC} = 4.5 V$	10	-2	-	13	-	15	-	ns
t _{su}	set-up time	Dn to CP; see Figure 9								
		$V_{CC} = 4.5 V$	12	5	-	15	-	18	-	ns
t _h	hold time	Dn to CP; see Figure 9								
		$V_{CC} = 4.5 V$	3	-4	-	3	-	3	-	ns
f _{max}	maximum	CP input; see Figure 7								
	frequency	$V_{CC} = 4.5 V$	30	56	-	24	-	20	-	MHz
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	36	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance	per package; 3 V _I = GND to V _{CC} - 1.5 V	<u>l</u> -	23	-	-	-	-	-	pF

Table 7. Dynamic characteristics ...continued

GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit, see Figure 10

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

 $\label{eq:ttilde} [2] \quad t_t \text{ is the same as } t_{THL} \text{ and } t_{TLH}.$

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

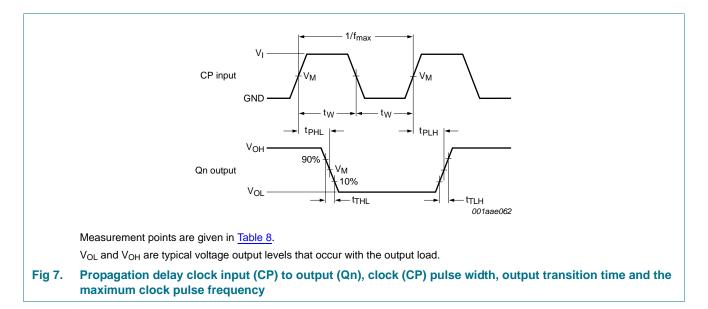
 Σ (C_L \times V_{CC}² \times f_o) = sum of outputs;

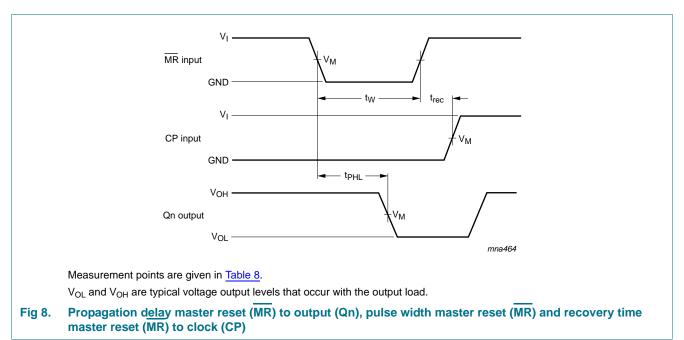
 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V.

Octal D-type flip-flop with reset; positive-edge trigger

11. Waveforms





74HC273; 74HCT273

Octal D-type flip-flop with reset; positive-edge trigger

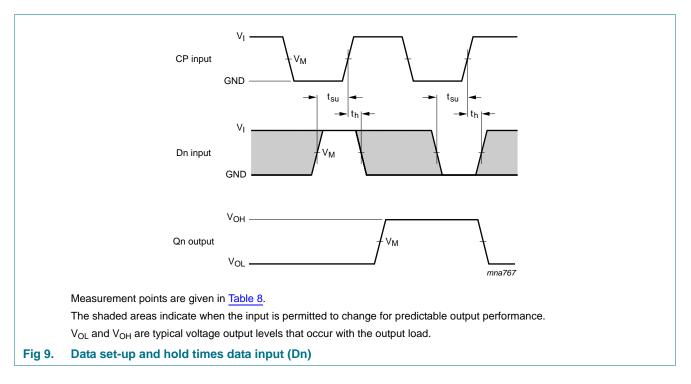


Table 8.Measurement points

Туре	Input	Output	
	VI	V _M	V _M
74HC273	V _{CC}	0.5V _{CC}	0.5V _{CC}
74HCT273	3 V	1.3 V	1.3 V

74HC273; 74HCT273

Octal D-type flip-flop with reset; positive-edge trigger

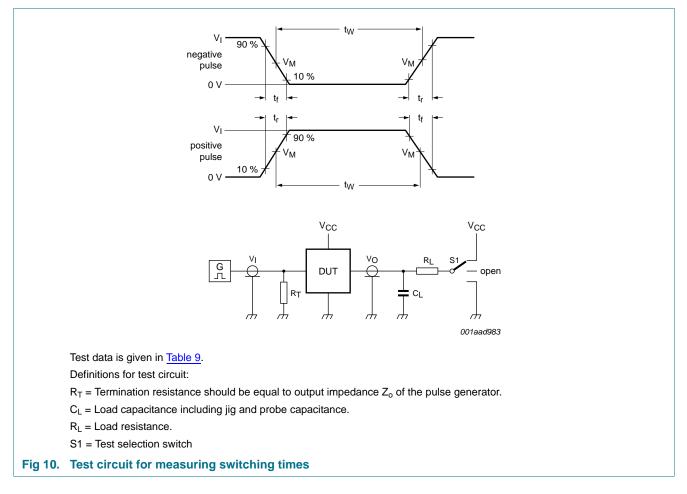


Table 9.Test data

Туре	e Input		Load		S1 position
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}
74HC273	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT273	3 V	6 ns	15 pF, 50 pF	1 kΩ	open

74HC273; 74HCT273

Octal D-type flip-flop with reset; positive-edge trigger

12. Package outline

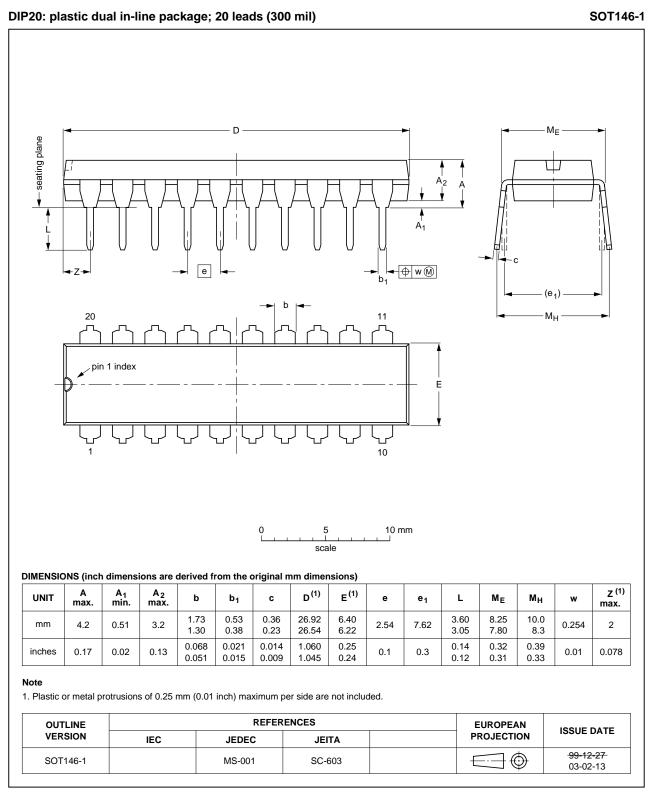


Fig 11. Package outline SOT146-1 (DIP20)

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Octal D-type flip-flop with reset; positive-edge trigger

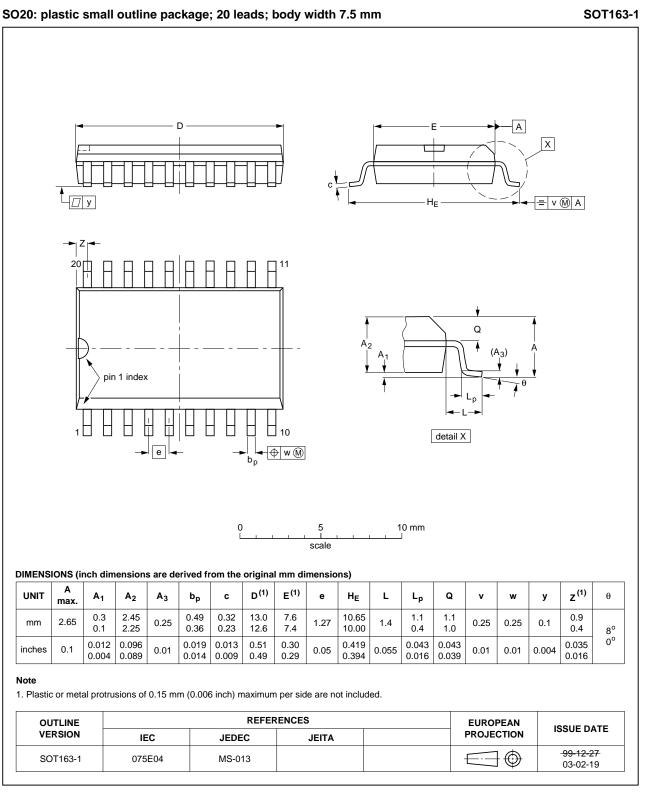


Fig 12. Package outline SOT163-1 (SO20)

Octal D-type flip-flop with reset; positive-edge trigger

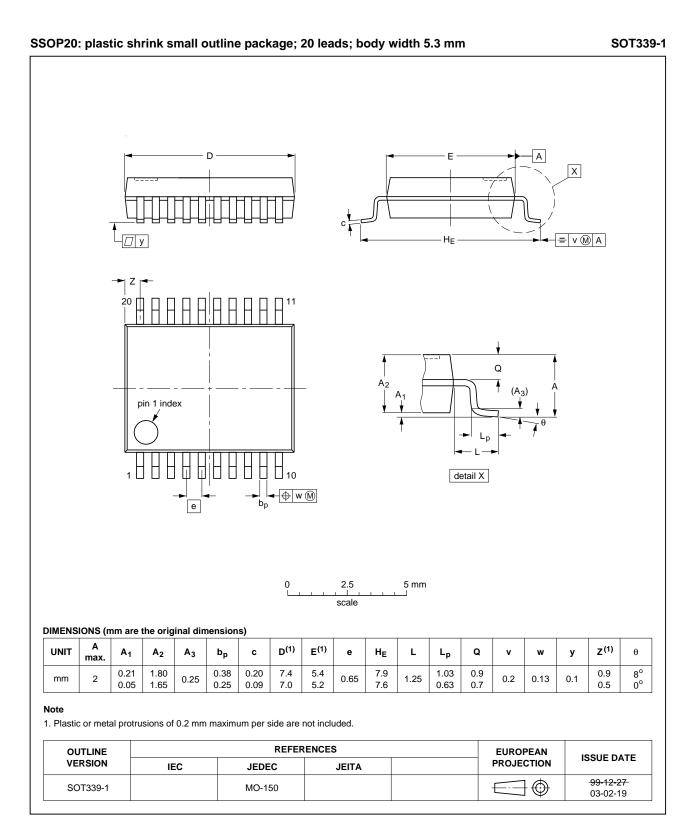


Fig 13. Package outline SOT339-1 (SSOP20)

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Octal D-type flip-flop with reset; positive-edge trigger

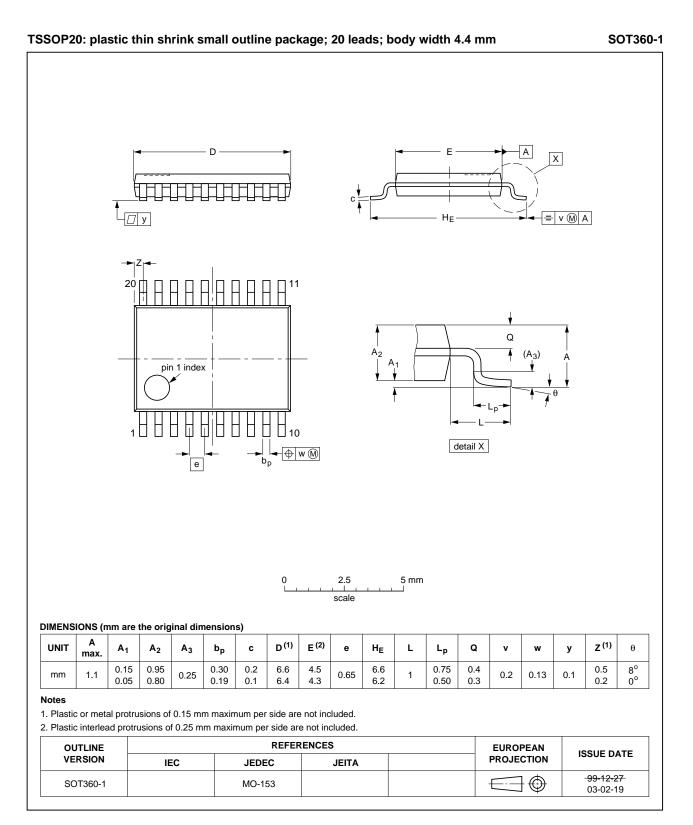
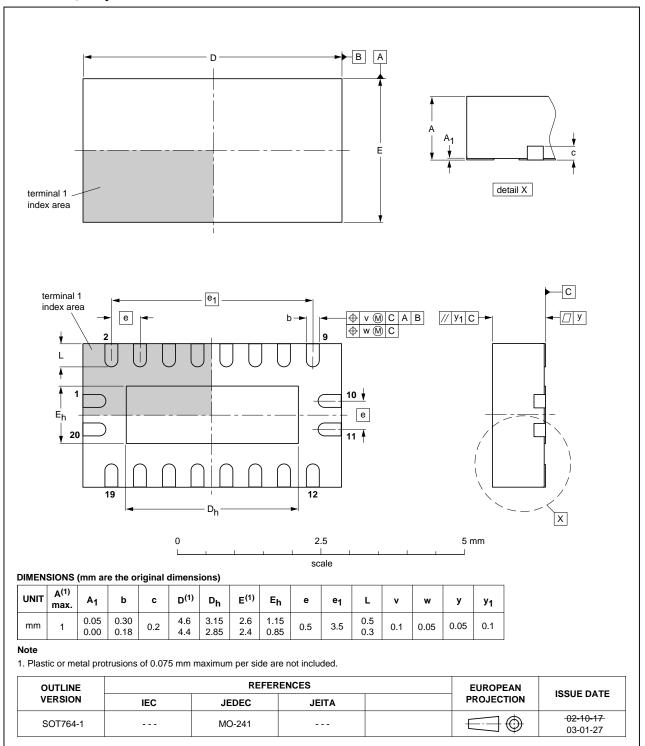


Fig 14. Package outline SOT360-1 (TSSOP20)

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Octal D-type flip-flop with reset; positive-edge trigger



DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

Fig 15. Package outline SOT764-1 (DHVQFN20)

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Octal D-type flip-flop with reset; positive-edge trigger

13. Abbreviations

Table 10. Abbreviations		
Acronym	Description	
CMOS	Complementary Metal-Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	
MM	Machine Model	
TTL	Transistor-Transistor Logic	

14. Revision history

Table 11. Revision histo	ry			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT273 v.4	20130610	Product data sheet	-	74HC_HCT273 v.3
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 			
	 Legal texts 	have been adapted to the	e new company name	where appropriate.
74HC_HCT273 v.3	20060124	Product data sheet	-	74HC_HCT273_CNV v.2
74HC_HCT273_CNV v.2	19970827	Product specification	-	-

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15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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